

#### **Medium Barrier Silicon Schottky Diodes**

Rev. V1

#### **Features**

- V<sub>F</sub>, R<sub>D</sub> and C<sub>J</sub> Matching Options
- Chip, Beam Lead and Packaged Devices
- Hi-Rel Screening per MIL-PRF-19500 and MIL-PRF-38534 Available

#### **Description**

The MSS40-xxx-x Series of Schottky diodes are fabricated on N-Type epitaxial substrates using proprietary processes that yield the highest FCOs in the industry. Optimum mixer performance is obtained with LO power of 0 dBm to +6 dBm per diode.



#### Chip

Electrical Specifications:  $T_A = 25$ °C

Model	Configuration	V <sub>F</sub> Typ. V	V <sub>BR</sub> Min. V	C <sub>J</sub> Typ. / Max. pF	R <sub>s</sub> Typ. Ω	R <sub>D</sub> Max. Ω	F <sub>co</sub> Typ. GHz	Outline
MSS40-045-C15	Single Junction	0.42	3	0.09 / 0.12	7	15	253	C15
MSS40-048-C15	Single Junction	0.40	3	0.12 / 0.15	7	15	190	C15
Test Conditions		I <sub>F</sub> = 1 mA	I <sub>R</sub> = 10 μA	$V_R = 0 V$ F = 1 MHz	I = 5 mA			

#### **Beam Lead**

Electrical Specifications: T<sub>A</sub> = 25°C

Model	Configuration	V <sub>F</sub> Typ. V	V <sub>BR</sub> Min. V	C <sub>J</sub> Typ. / Max. pF	R <sub>s</sub> Typ. Ω	$R_D$ Max.	F <sub>co</sub> Typ. GHz	Outline
MSS40-141-B10B	Single Junction	0.42	3	0.06 / 0.10	10	22	265	B10B
MSS40-148-B10B	Single Junction	0.40	3	0.12 / 0.15	7	17	190	B10B
MSS40-155-B10B	Single Junction	0.38	3	0.25 / 0.30	5	13	127	B10B
MSS40-244-B20	Series Tee	0.44	3	0.08 / 0.12	19	22	105	B20
MSS40-248-B20	Series Tee	0.44	3	0.12 / 0.15	10	17	133	B20
MSS40-255-B20	Series Tee	0.38	3	0.25 / 0.30	5	15	127	B20
MSS40-448-B41	Ring Quad	0.40	3	0.12 / 0.15	7	17	190	B41
MSS40-455-B40	Ring Quad	0.38	3	0.25 / 0.30	5	17	127	B40
Test Conditions		I <sub>F</sub> = 1 mA	Ι <sub>R</sub> = 10 μΑ	$V_R = 0 V$ F = 1 MHz	I = 5	5 mA		

(Continued next page)



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#### **Packaged**

Electrical Specifications: T<sub>A</sub> = 25°C

Model	Configuration	V <sub>F</sub> Typ. V	V <sub>BR</sub> Min. V	C <sub>J</sub> Typ. / Max. pF	R <sub>s</sub> Typ. Ω	R <sub>D</sub> Max. Ω	F <sub>co</sub> Typ. GHz	Outline
MSS40-045-P55	Single Junction	0.42	3	0.21 / 0.27	7		253	P55
MSS40-045-P86	Single Junction	0.42	3	0.24 / 0.30	7		253	P86
MSS40-048-P55	Single Junction	0.40	3	0.24 / 0.30	7		190	P55
MSS40-048-P86	Single Junction	0.40	3	0.27 / 0.33	7		190	P86
MSS40-141-E25	Single Junction	0.42	3	0.16 / 0.22	10		265	E25
MSS40-141-H20	Single Junction	0.42	3	0.24 / 0.30	10		265	H20
MSS40-148-E25	Single Junction	0.40	3	0.22 / 0.28	7		190	E25
MSS40-148-H20	Single Junction	0.40	3	0.30 / 0.36	7		190	H20
MSS40-155-E25	Single Junction	0.38	3	0.35 / 0.41	5		127	E25
MSS40-155-H20	Single Junction	0.38	3	0.43 / 0.50	5		127	H20
MSS40-244-E35	Series Tee	0.44	3	0.18 / 0.24	19		105	E35
MSS40-248-E35	Series Tee	0.44	3	0.22 / 0.28	10		133	E35
MSS40-255-E35	Series Tee	0.38	3	0.35 / 0.41	5		127	E35
MSS40-448-E45	Ring Quad	0.40	3	0.24 / 0.30	7		190	E45
MSS40-455-E45	Ring Quad	0.38	3	0.32 / 0.38	5		127	E45
MSS40-455-H40	Ring Quad	0.38	3	0.42 / 0.48	5		127	H40
Test Conditions		I <sub>F</sub> = 1 mA	Ι <sub>R</sub> = 10 μΑ	$V_R = 0 V$ F = 1 MHz	I = 5	i mA		

### **Absolute Maximum Ratings**

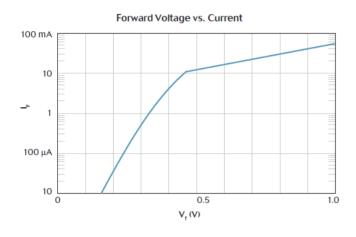
Parameters	Rating				
Reverse Voltage	Rated V <sub>BR</sub>				
Forward Current	50 mA				
Power Dissipation	100 mW, per junction @ $T_A$ = 25°C, derate linearly to 0 @ $T_A$ = +150°C				
Operating Temperature	-65°C to +150°C				
Storage Temperature	-65°C to +150°C				
Soldering Temperature (packaged)	+230°C for 5 seconds				
Beam Lead Pull Strength	4 G minimum				

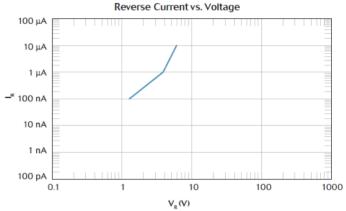


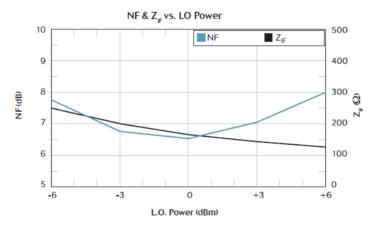
## **Medium Barrier Silicon Schottky Diodes**

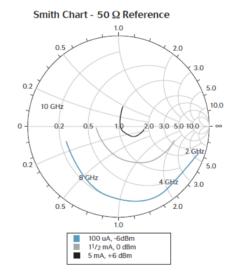
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## Typical Performance Curves: T<sub>A</sub> = 25°C







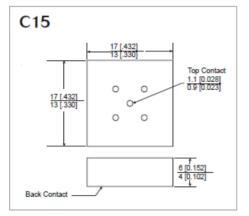


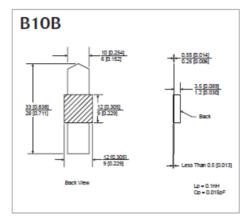


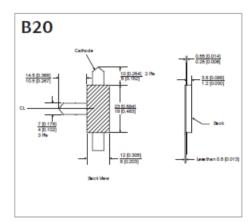
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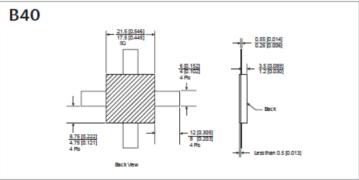
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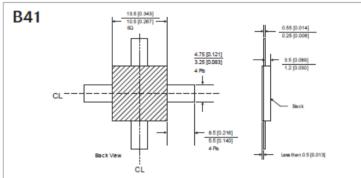
#### **Outline Drawings**

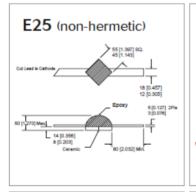


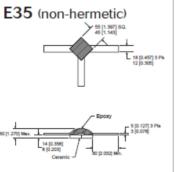


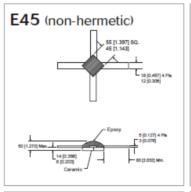


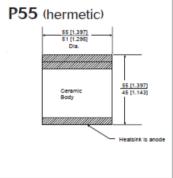


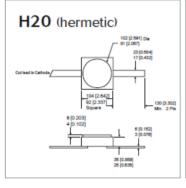


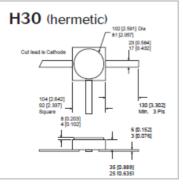


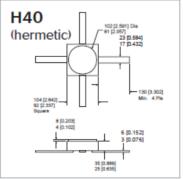


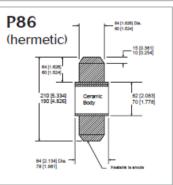












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